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TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

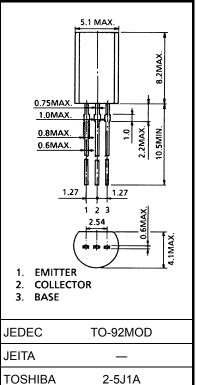
2SC2655

Power Amplifier Applications Power Switching Applications

- Low saturation voltage: V_{CE} (sat) = 0.5 V (max) (IC = 1 A)
- High collector power dissipation: $P_C = 900 \text{ mW}$
- High-speed switching: $t_{stg} = 1.0 \ \mu s \ (typ.)$
- Complementary to 2SA1020.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	50	V	
Collector-emitter voltage	V _{CEO}	50	V	
Emitter-base voltage	V _{EBO}	5	V	
Collector current	ΙC	2	А	
Base current	Ι _Β	0.5	А	
Collector power dissipation	P _C	900	mW	
Junction temperature	Tj	150	°C	
Storage temperature range	T _{stg}	-55 to 150	°C	



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

Weight: 0.36 g (typ.)

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

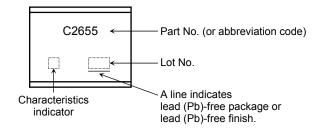
Industrial Applications Unit: mm

Electrical Characteristics (Ta = 25°C)

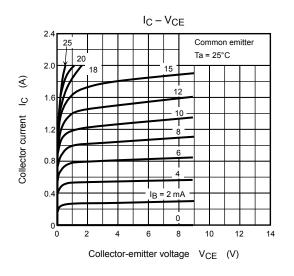
Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off cu	urrent	I _{CBO}	V _{CB} = 50 V, I _E = 0	_	_	1.0	μA
Emitter cut-off cur	rent	I _{EBO}	V _{EB} = 5 V, I _C = 0		_	1.0	μA
Collector-emitter b	oreakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	50	_	_	V
DC current gain		h _{FE (1)} (Note)	V _{CE} = 2 V, I _C = 0.5 A	70	_	240	
		h _{FE (2)}	V _{CE} = 2 V, I _C = 1.5 A	40	_	_	
Collector-emitter s	aturation voltage	V _{CE (sat)}	I _C = 1 A, I _B = 0.05 A	_	_	0.5	V
Base-emitter satur	ration voltage	V _{BE (sat)}	I _C = 1 A, I _B = 0.05 A	_	_	1.2	V
Transition frequency		f _T	V _{CE} = 2 V, I _C = 0.5 A	_	100	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _C = 0, f = 1 MHz	_	30	_	pF
Switching time	Turn-on time	t _{on}	$20 \ \mu s \qquad \text{Input} \qquad B1 \qquad Output \\ \xrightarrow{\underline{m}} \qquad $	_	0.1	_	
	Storage time	t _{stg}		_	1.0	_	μs
	Fall time	t _f	30 V I _{B1} = −I _{B2} = 0.05 A, duty cycle ≤ 1%		0.1	_	

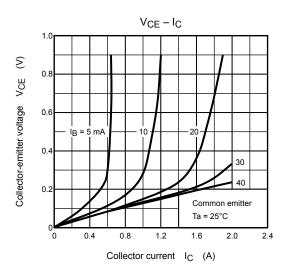
Note: hFE (1) classification O: 70 to 140, Y: 120 to 240

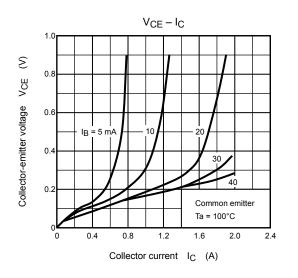
Marking

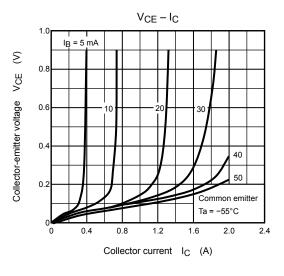


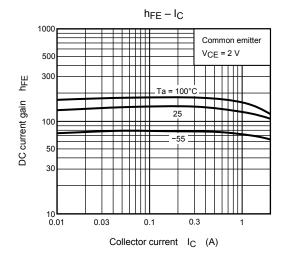
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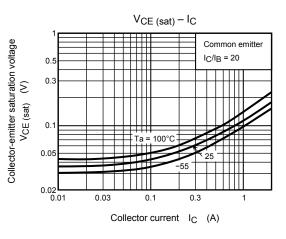




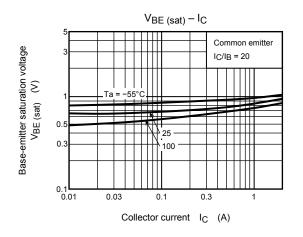


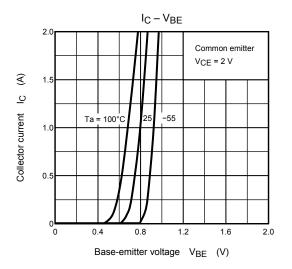


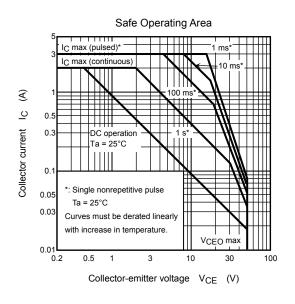


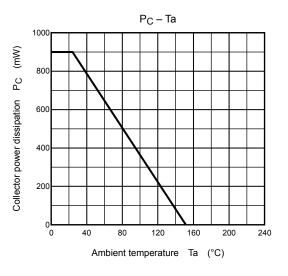


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